

PQMD3

NPN/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

26 October 2015

Product data sheet

1. General description

NPN/PNP double Resistor-Equipped Transistors (RET) in a leadless ultra small DFN1010B-6 (SOT1216) Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PQMH11
PNP/PNP complement: PQMB11

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Low package height of 0.37 mm
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications
- Mobile applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor;	Per transistor; for the PNP transistor with negative polarity							
V _{CEO}	collector-emitter voltage	open base		-	-	50	V	
I _O	output current			-	-	100	mA	
Per transistor; for the PNP transistor with negative polarity								
R1	bias resistor 1	T _{amb} = 25 °C	[1]	7	10	13	kΩ	
R2/R1	bias resistor ratio		[1]	8.0	1	1.2		

^[1] See section "Test information" for resistor calculation and test conditions.



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1	500	O1 I2 GND2
2	I1	input (base) TR1	$\begin{bmatrix} 1 \\ 7 \end{bmatrix} \begin{bmatrix} 6 \\ \end{bmatrix}$	
3	O2	output (collector) TR2	2 5	R1 R2
4	GND2	GND (emitter) TR2		TR1 TR2
5	12	input (base) TR2	3 4	R2 R1
6	O1	output (collector) TR1	Transparent top view	
7	O1	output (collector) TR1	DFN1010B-6 (SOT1216)	GND1 I1 O2 aaa-007379
8	O2	output (collector) TR2		dad 557575

6. Ordering information

Table 3. Ordering information

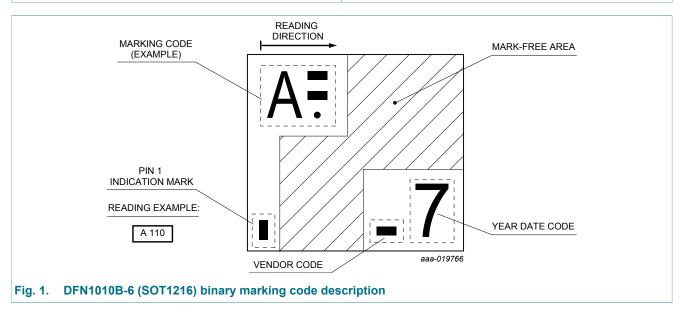
Type number	Package				
	Name	Description	Version		
PQMD3	DFN1010B-6	DFN1010B-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1216		

NPN/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

7. Marking

Table 4. Marking codes

Type number	Marking code
PQMD3	A 111



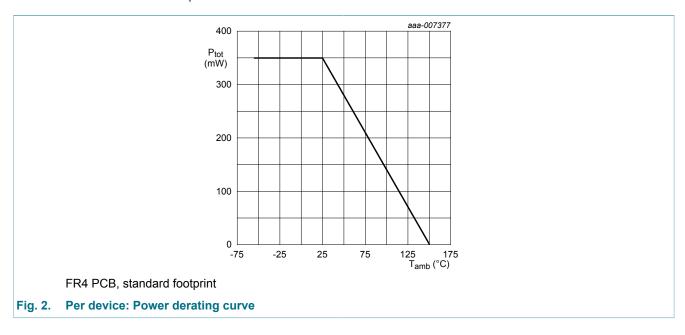
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transis	tor; for the PNP transistor with	negative polarity				
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	10	V
V _I input vo	input voltage	TR1; positive		-	40	V
		TR1; negative		-	-10	V
		TR2; positive		-	10	V
		TR2; negative		-	-40	V
I _O	output current			-	100	mA
I _{CM}	peak collector current	t _p ≤ 1 ms; single pulse		-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	230	mW
Per device			'			
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	350	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



PQMD3

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	Per transistor						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	543	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	357	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

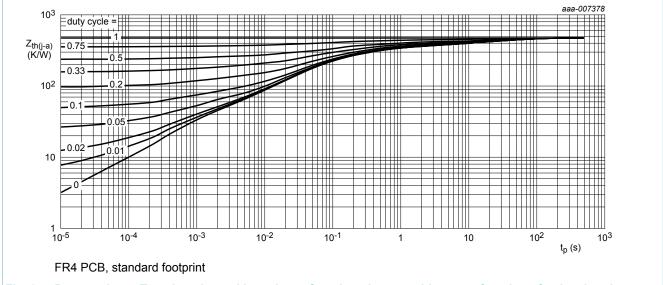


Fig. 3. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

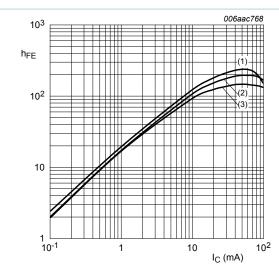
10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	tor; for the PNP transistor	with negative polarity			'		
I _{CBO}	collector-base cut-off current (emitter open)	$V_{CB} = 50 \text{ V}; I_{E} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	100	nA
I _{CEO}	collector-emitter cut-off	V_{CE} = 30 V; I_{B} = 0 A; T_{amb} = 25 °C		-	-	1	μA
	current (base open)	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 150 °C		-	-	5	μA
I _{EBO}	emitter-base cut-off current (collector open)	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	400	μA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		30	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 \text{ °C}$		-	-	150	mV
V _{I(off)}	off-state input voltage	V_{CE} = 5 V; I_{C} = 100 μ A; T_{amb} = 25 °C		-	1.1	0.8	V
V _{I(on)}	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 10 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		2.5	1.8	-	V
R1	bias resistor 1	T _{amb} = 25 °C	[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
C _C	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = 0 \text{ A}; f = 1 \text{ MHz};$ $T_{amb} = 25 ^{\circ}\text{C}; TR1 \text{ (NPN)}$		-	-	2.5	pF
		V_{CB} = -10 V; I_E = 0 A; f = 1 MHz; T_{amb} = 25 °C; TR2 (PNP)		-	-	3	pF
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 10 mA; f = 100 MHz; T_{amb} = 25 °C; TR1 (NPN)	[2]	-	230	-	MHz
		$V_{CE} = -5 \text{ V}; I_{C} = -10 \text{ mA}; f = 100 \text{ MHz};$ $T_{amb} = 25 \text{ °C}; TR2 (PNP)$	[2]	-	180	-	MHz

^[1] See section "Test information" for resistor calculation and test conditions.

^[2] Characteristics of built-in transistor



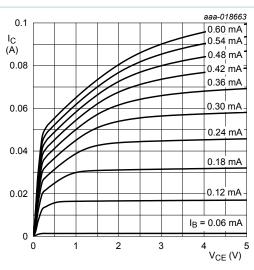
 $V_{CE} = 5 V$

(1) $T_{amb} = 100 \, ^{\circ}C$

(2) $T_{amb} = 25 \, ^{\circ}C$

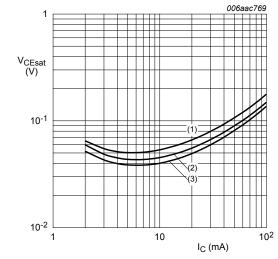
(3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 4. NPN transistor: DC current gain as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$

Fig. 5. NPN transistor: Collector current as a function of collector-emitter voltage; typical values



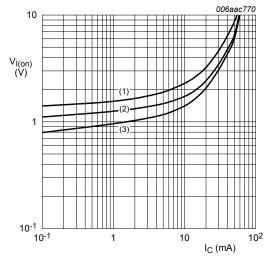
 $I_{\rm C}/I_{\rm B} = 20$

(1) $T_{amb} = 100 \, ^{\circ}C$

(2) T_{amb} = 25 °C

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 6. NPN transistor: Collector-emitter saturation voltage as a function of collector current; typical values



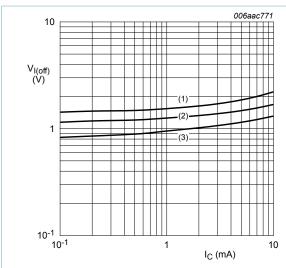
 $V_{CE} = 0.3 V$

(1) $T_{amb} = -40 \, ^{\circ}C$

(2) T_{amb} = 25 °C

(3) $T_{amb} = 100 \, ^{\circ}C$

Fig. 7. NPN transistor: On-state input voltage as a function of collector current; typical values



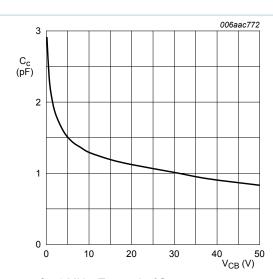
$$V_{CE} = 5 V$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

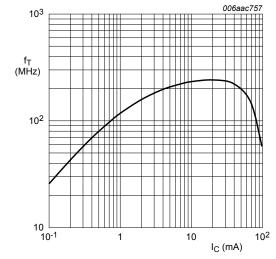
(3) $T_{amb} = 100 \, ^{\circ}C$

Fig. 8. NPN transistor: Off-state input voltage as a function of collector current; typical values



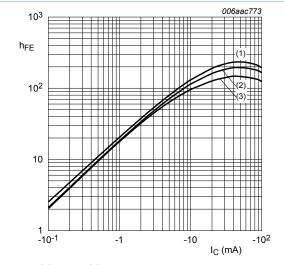
 $f = 1 MHz; T_{amb} = 25 °C$

Fig. 9. NPN transistor: Collector capacitance as a function of collector-base voltage; typical values



 V_{CE} = 5 V; T_{amb} = 25 °C

Fig. 10. NPN transistor: Transition frequency as a function of collector current; typical values of built-in transistor



 $V_{CE} = -5 V$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2) T_{amb} = 25 °C

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 11. PNP transistor: DC current gain as a function of collector current; typical values

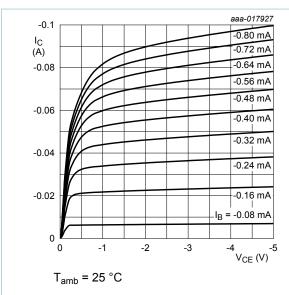
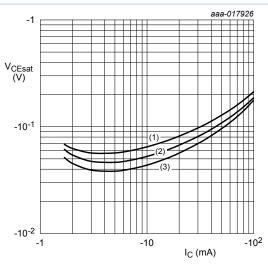


Fig. 12. PNP transistor: Collector current as a function of collector-emitter voltage; typical values



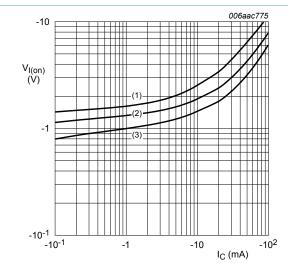
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 13. PNP transistor: Collector-emitter saturation voltage as a function of collector current; typical values



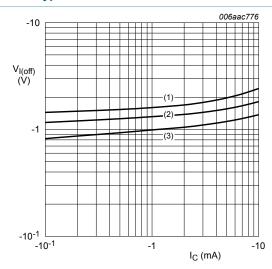
$$V_{CE}$$
 = -0.3 V

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 14. PNP transistor: On-state input voltage as a function of collector current; typical values



$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 15. PNP transistor: Off-state input voltage as a function of collector current; typical values

NPN/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

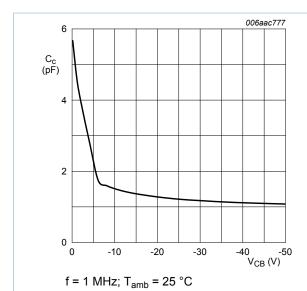


Fig. 16. PNP transistor: Collector capacitance as a function of collector-base voltage; typical values

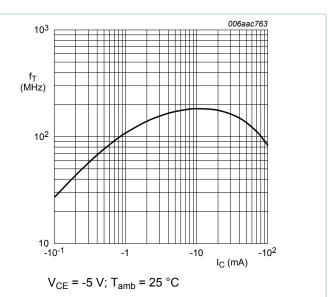


Fig. 17. PNP transistor: Transition frequency as a function of collector current; typical values of built-in transistor

11. Test information

11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

11.2 Resistor calculation

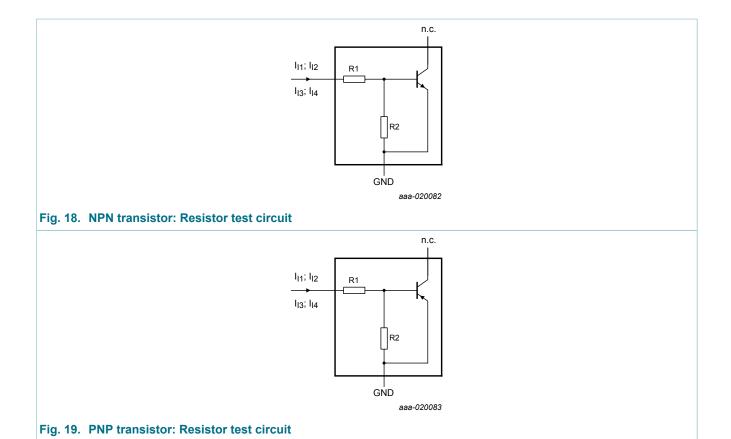
Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I_{12}) - V(I_{11})}{I_{12} - I_{11}}$$

Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$

NPN/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω



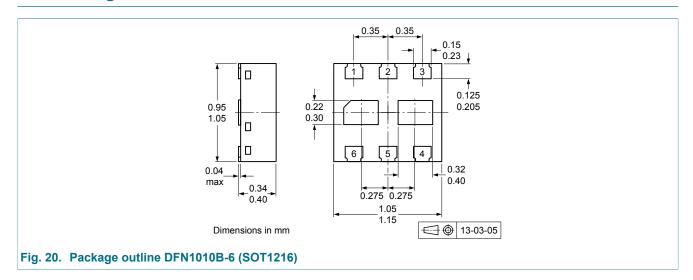
11.3 Resistor test conditions

Table 8. Resistor test conditions

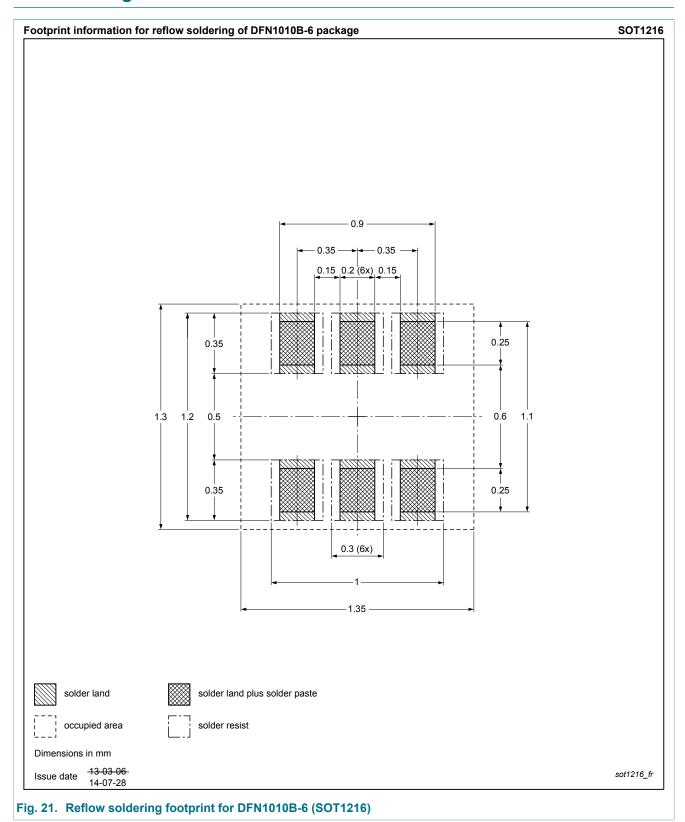
Per transistor; for the PNP transistor with negative polarity

R1 (kΩ)	R2 (kΩ)	Test conditions			
		I _{I1}	I _{I2}	I _{I3}	I _{I4}
10	10	350 μΑ	450 μA	-350 μA	-450 μA

12. Package outline



13. Soldering



PQMD3

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NPN/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PQMD3 v.1	20151026	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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16. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	
7	Marking	
8	Limiting values	
9	Thermal characteristics	
10	Characteristics	
11	Test information	10
11.1	Quality information	
11.2	Resistor calculation	
11.3	Resistor test conditions	11
12	Package outline	12
13	Soldering	13
14	Revision history	14
15	Legal information	
15.1	Data sheet status	
15.2	Definitions	15
15.3	Disclaimers	15
15.4	Trademarks	16

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